

### FEATURES

- Available in the Texas Instruments NanoStar<sup>™</sup> and NanoFree<sup>™</sup> Packages
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 3.9 ns at 3.3 V
- Low Power Consumption, 10-µA Max I<sub>cc</sub>
- ±24-mA Output Drive at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
  2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Unbuffered Outputs
- Latch-Up Performance Exceeds 100 mA
  Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## **DESCRIPTION/ORDERING INFORMATION**

This triple inverter is designed for 1.65-V to 5.5-V  $V_{CC}$  operation.

The SN74LVC3GU04 contains three inverters with unbuffered outputs and performs the Boolean function  $Y = \overline{A}$ .

NanoStar<sup>™</sup> and NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>
-40°C to 85°C	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Reel of 3000	SN74LVC3GU04YEPR	CD
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel 01 3000	SN74LVC3GU04YZPR	CD_
	SSOP – DCT	Reel of 3000	SN74LVC3GU04DCTR	CU4
	VSSOP – DCU	Reel of 3000	SN74LVC3GU04DCUR	CU4
	V330F - DC0	Reel of 250	SN74LVC3GU04DCUT	0.04_

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, · = Pb-free).



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]2Y

YEP OR YZP PACKAGE (BOTTOM VIEW)

GND [

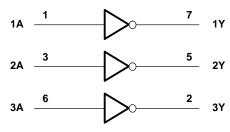
4

GND 2A 3Y	04	50	2Y
2A	03	60	3A
3Y	02	70	1Y
1A	01	80	Vcc

### FUNCTION TABLE (EACH INVERTER)

INPUT A	OUTPUT Y
Н	L
L	Н

### LOGIC DIAGRAM (POSITIVE LOGIC)



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range	-0.5	6.5	V	
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Output voltage range <sup>(2)(3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through $V_{CC}$ or GND			±100	mA
		DCT package		220	
$\theta_{JA}$ Package thermal impedance <sup>(4)</sup>		DCU package		227	°C/W
		YEP/YZP package		102	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

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## **Recommended Operating Conditions**<sup>(1)</sup>

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		1.65	5.5	V
$V_{\text{IH}}$	High-level input voltage	I <sub>O</sub> = −100 μA	0.75 × V <sub>CC</sub>		V
V <sub>IL</sub>	Low-level input voltage	I <sub>O</sub> = 100 μA		$0.25 \times V_{CC}$	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
		$V_{CC} = 2.3 V$		-8	
I <sub>OH</sub>	High-level output current	V 2.V		-16	mA
	V <sub>CC</sub> = 3 V	$V_{CC} = 3 V$		-24	
		$V_{CC} = 4.5 V$		-32	
		V <sub>CC</sub> = 1.65 V		4	
		$V_{CC} = 2.3 V$		8	
I <sub>OL</sub>	Low-level output current	V 2.V		16	mA
		$V_{CC} = 3 V$		24	
		$V_{CC} = 4.5 V$		32	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TES	<b>CONDITIONS</b>	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup> MAX	UNIT
		I <sub>OH</sub> = -100 mA	1.65 V to 5.5 V	V <sub>CC</sub> – 0.1		
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
V	$V_{II} = 0 V$	I <sub>OH</sub> = -8 mA	2.3 V	1.9		V
V <sub>OH</sub>	V <sub>IL</sub> = 0 V	I <sub>OH</sub> = -16 mA	3 V	2.4		v
		I <sub>OH</sub> = -24 mA	3 V	2.3		
		I <sub>OH</sub> = -32 mA	4.5 V	3.8		
		I <sub>OL</sub> = 100 mA	1.65 V to 5.5 V		0.1	
		$I_{OL} = 4 \text{ mA}$	1.65 V		0.45	
V		I <sub>OL</sub> = 8 mA	2.3 V		0.3	V
V <sub>OL</sub>	$V_{IH} = V_{CC}$	I <sub>OL</sub> = 16 mA	3 V		0.4	v
		I <sub>OL</sub> = 24 mA	3 V		0.55	
		I <sub>OL</sub> = 32 mA	4.5 V		0.55	
l <sub>l</sub>	$V_{I} = 5.5 \text{ V or GND}$		0 to 5.5 V		±5	μA
I <sub>CC</sub>	$V_I = 5.5 V \text{ or GND},$	I <sub>O</sub> = 0	1.65 V to 5.5 V		10	μA
Ci	$V_{I} = V_{CC}$ or GND		3.3 V		7	pF

(1) All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.

# SN74LVC3GU04 TRIPLE INVERTER GATE

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### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = ± 0.1		V <sub>CC</sub> = ± 0.2		V <sub>CC</sub> = ± 0.3		V <sub>CC</sub> = ± 0.5		UNIT
	(INFUT)	(001-01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	А	Y	0.2	9.2	0.2	4	0.6	3.9	0.5	3.2	ns

## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	$V_{CC}$ = 2.5 V	V <sub>CC</sub> = 3.3 V	$V_{CC} = 5 V$	UNIT
			TYP	TYP	TYP	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	8	8	11	23	pF

VI

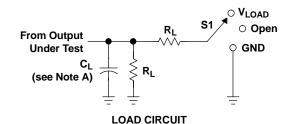
0 V

٧ı

0 V

Vм

PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

Vм

th

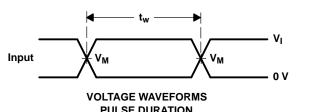
t<sub>su</sub>

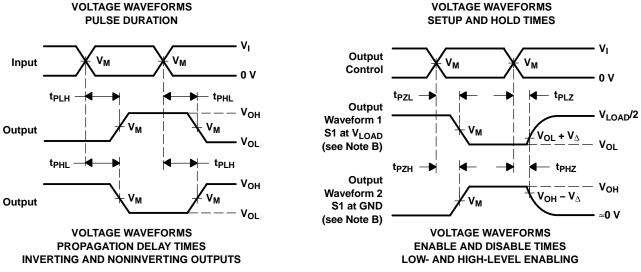
Vм

N/	INPUTS		V	V	•		N
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	VM	V <sub>LOAD</sub>	CL	RL	$V_\Delta$
1.8 V $\pm$ 0.15 V	v <sub>cc</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	Vcc	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>500</b> Ω	0.15 V
3.3 V $\pm$ 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V
5 V $\pm$ 0.5 V	V <sub>CC</sub>	≤2.5 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	50 pF	<b>500</b> Ω	0.3 V

**Timing Input** 

**Data Input** 





- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z\_{O} = 50  $\Omega$ .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H. All parameters and waveforms are not applicable to all devices.

### Figure 1. Load Circuit and Voltage Waveforms

### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	n MSL Peak Temp <sup>(3)</sup>
74LVC3GU04DCTRE4	ACTIVE	SM8	DCT	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
74LVC3GU04DCURE4	ACTIVE	US8	DCU	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC3GU04DCTR	ACTIVE	SM8	DCT	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC3GU04DCUR	ACTIVE	US8	DCU	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC3GU04YEPR	ACTIVE	WCSP	YEP	8	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74LVC3GU04YZPR	ACTIVE	WCSP	YZP	8	3000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

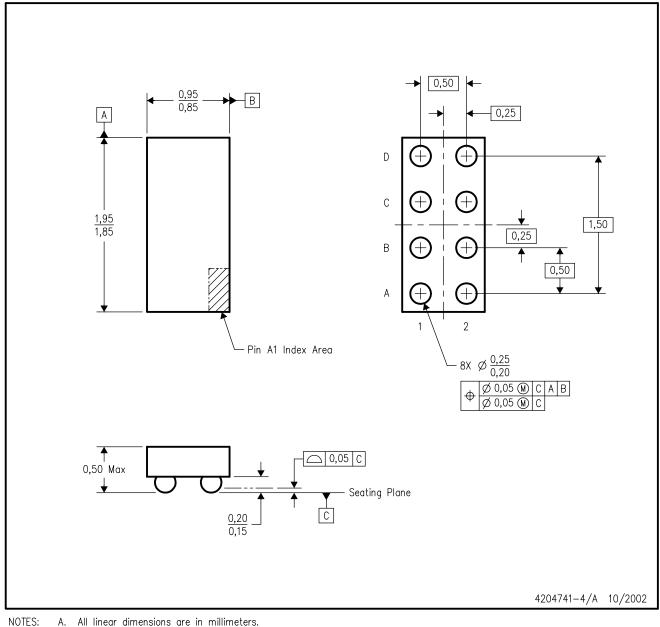
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



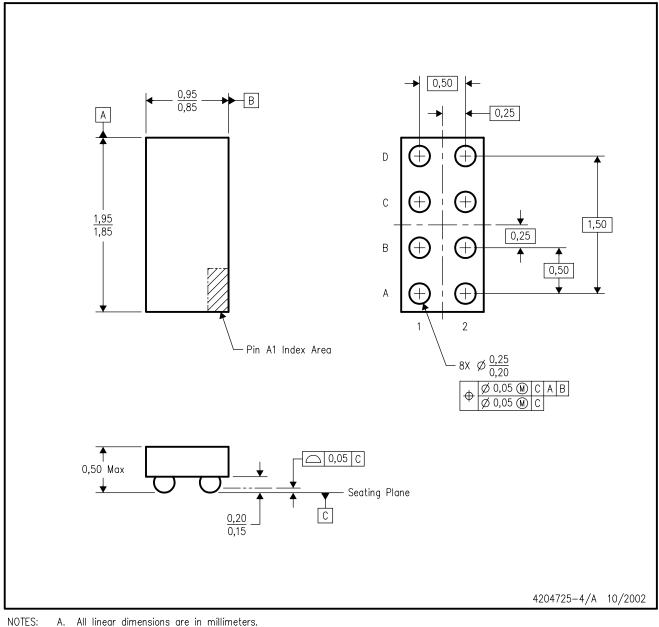
- A. All linear dimensions are in millimeters. B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

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YEP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice. C. NanoStar™ package configuration.
- D. This package is tin-lead (SnPb). Refer to the 8 YZP package (drawing 4204741) for lead-free.

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